NXP BYC30WT-600P diode datasheet

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Hyperfast power diode in a SOT429 (3-lead TO247) plastic package.

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Product data sheet

1. General description

Hyperfast power diode in a SOT429 (3-lead TO247) plastic package.

2. Features and benefits

- Low leakage current
- Low thermal resistance
- Low reverse recovery current
- Reduces switching losses in associated MOSFET or IGBT

3. Applications

- Active PFC in air conditioner
- Continuous Current Mode (CCM) Power Factor Correction (PFC)
- Half-bridge/full-bridge switched-mode power supplies

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{F(AV)}	average forward current	δ = 0.5; T _{mb} ≤ 115 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	-	30	A
Static chara	cteristics					
V _F	forward voltage	I _F = 30 A; T _j = 150 °C; <u>Fig. 6</u>	-	1.38	1.8	V
Dynamic ch	aracteristics	· · · · · · · · · · · · · · · · · · ·				
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	18	22	ns





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5. Pinning information

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A	anode		K – A
2	К	cathode		001aaa020
3	А	anode		
mb	mb	mounting base; connected to cathode	TO-247 (SOT429)	

6. Ordering information

Table 3. Ordering information							
Type number	Package						
	Name	Description	Version				
BYC30WT-600P	TO-247	plastic single-ended through-hole package; heatsink mounted; 1 mounting hole; 3 lead TO-247	SOT429				

7. Marking

Table 4. Marking codes	
Type number	Marking code
BYC30WT-600P	BYC30WT-600P

8. Limiting values

Table 5.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
V _{RRM}	repetitive peak reverse voltage		-	600	V
V _{RWM}	crest working reverse voltage		-	600	V
V _R	reverse voltage	DC	-	600	V
I _{F(AV)}	average forward current	δ = 0.5; T _{mb} ≤ 115 °C; square-wave pulse; Fig. 1; Fig. 2; Fig. 3	-	30	A
I _{FRM}	repetitive peak forward current	$\begin{split} &\bar{\sigma} = 0.5; t_p = 25 \; \mu s; T_{mb} \leq 115 \; ^\circ C; \\ & \text{square-wave pulse} \end{split}$	-	60	A

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 Product data sheet
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 2 / 9

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BYC30WT-600P

Hyperfast power diode

Symbol	Parameter	Conditions	Min	Max	Unit
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	270	A
		t_p = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	-	300	A
T _{stg}	storage temperature		-65	175	°C
Tj	junction temperature		-	175	°C

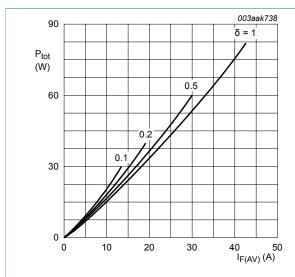
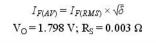
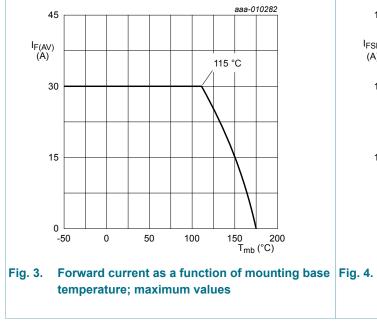


Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values





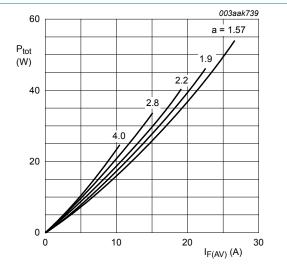
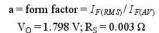
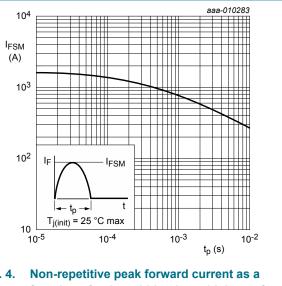


Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values





function of pulse width; sinusoidal waveform; maximum values

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BYC30WT-600P

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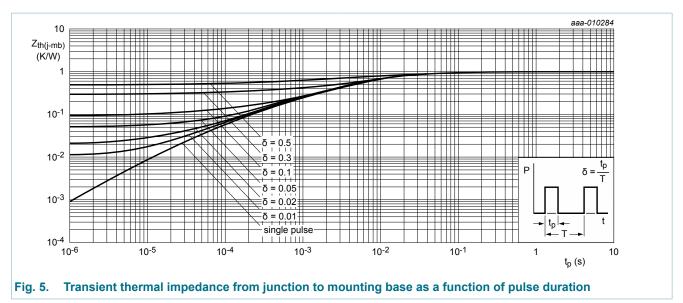
3/9

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Hyperfast power diode

9. Thermal characteristics

Table 6. The	rmal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	with heatsink compound; Fig. 5	-	-	1	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	in free air	-	45	-	K/W



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics	· · · · · ·	I.			
V _F	forward voltage	I _F = 30 A; T _j = 25 °C; <u>Fig. 6</u>	-	2	2.75	V
		I _F = 30 A; T _j = 150 °C; <u>Fig. 6</u>	-	1.38	1.8	V
I _R	reverse current	V _R = 600 V; T _j = 25 °C	-	-	10	μA
		V _R = 600 V; T _j = 150 °C	-	-	1	mA
Dynamic cl	naracteristics					
Q _r	recovered charge	$I_F = 30 \text{ A}; V_R = 200 \text{ V}; dI_F/dt = 200 \text{ A}/$ μ s; T _j = 25 °C; <u>Fig. 7</u>	-	50	-	nC
		I _F = 30 A; V _R = 200 V; dI _F /dt = 200 A/ μs; T _i = 125 °C; <u>Fig. 7</u>	-	280	-	nC

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 4 / 9

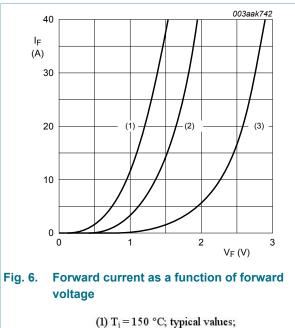
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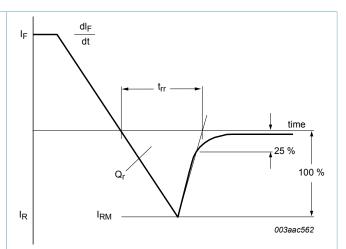
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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
t _{rr}	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 200 \text{ A}/\mu\text{s};$ $T_j = 25 \text{ °C}; Fig. 7$	-	18	22	ns
	I _F = 30 A; V _R = 200 V; dI _F /dt = 200 A/ μs; T _j = 25 °C; <u>Fig. 7</u>	-	35	-	ns	
		I _F = 30 A; V _R = 200 V; dI _F /dt = 200 A/ μs; T _j = 125 °C; <u>Fig. 7</u>	-	70	-	ns
		I _F = 30 A; V _R = 400 V; dI _F /dt = 500 A/ μs; T _j = 25 °C; <u>Fig. 7</u>	-	29	-	ns
I _{RM}	peak reverse recovery current	I _F = 30 A; V _R = 200 V; dI _F /dt = 200 A/ μs; T _j = 25 °C; <u>Fig. 7</u>	-	3.5	-	A
		I_F = 30 A; V_R = 200 V; dI_F/dt = 200 A/ µs; T_j = 125 °C; <u>Fig. 7</u>	-	7.6	-	A



(2) $T_j = 150$ °C; maximum values; (3) $T_j = 25$ °C; maximum values; $V_0 = 1.798$ V; $R_S = 0.003 \Omega$





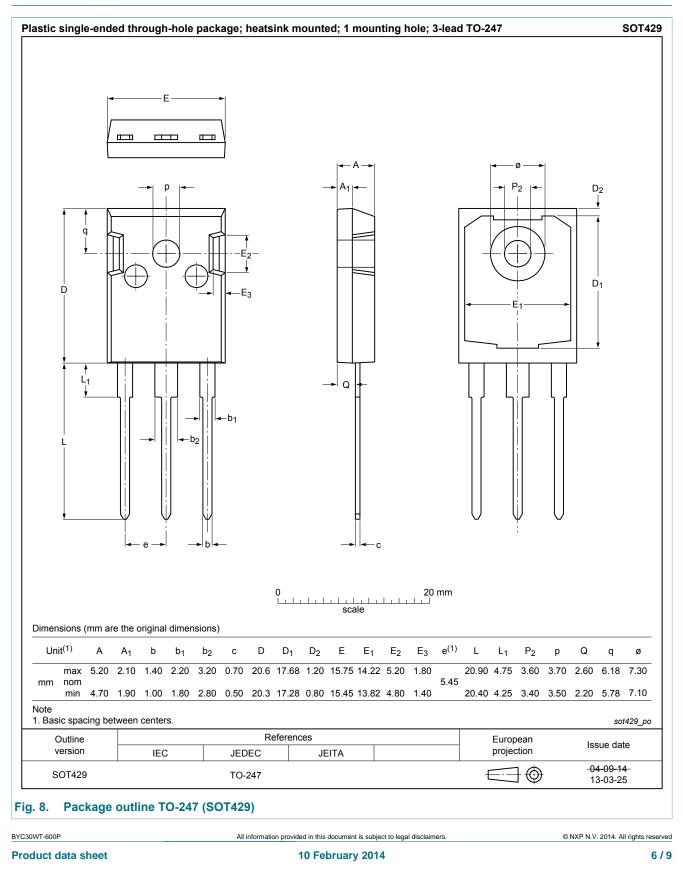
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11. Package outline



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12. Legal information

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Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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7/9

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8/9

Product data sheet

10 February 2014

Hyperfast power diode

13. Contents

General description	. 1
Features and benefits	.1
Applications	1
Quick reference data	. 1
Pinning information	.2
Ordering information	.2
Marking	. 2
Limiting values	.2
Thermal characteristics	.4
Characteristics	.4
Package outline	6
Legal information	.7
Data sheet status	. 7
Definitions	.7
Disclaimers	.7
Trademarks	8
	Features and benefits

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